ASD ${ }^{\text {™ }}$
AC Switch Family

## MAIN APPLICATIONS

- AC on-off static switching in appliance control systems
- Drive of low power high inductive or resistive loads like
- relay, valve, solenoid, dispenser
- pump, fan, micro-motor
- low power lamp bulb, door lock


## FEATURES

- Blocking voltage : VDRM / VRRM $=500 \mathrm{~V}$
- Clamping voltage : VCL $=600 \mathrm{~V}$
- Nominal current : $\mathrm{I}_{\text {(RMS })}=0.2 \mathrm{~A}$
- Gate triggering current : IGT $<5 \mathrm{~mA}$
- Switch integrated driver
- SO-8 package:
- drive reference COM connected to 2 cooling pins
-3 mm creepage distance from pin OUT to other pins


## BENEFITS

- Needs no more external protection snubber or varistor
- Enables equipment to meet IEC 1000-4-5 \& IEC 335-1
- Reduces component count by up to $80 \%$
- Interfaces directly with a microcontroller
- Eliminates any stressing gate kick back on microcontroller
- Allows straightforward connection of several ACS on same cooling pad


## DESCRIPTION

The ACS102 belongs to the AC line switch family built around the ASD concept. This high performance 5 mA switch circuit is able to control an up to 0.3 A load.
The ACS switch embeds a high voltage clamping structure to absorb the inductive turn off energy and a gate level shifter driver to separate the digital controller from the main switch. It is triggered with a negative gate current flowing out of the gate pin.

PRELIMINARY DATASHEET


FUNCTIONAL DIAGRAM


ACS102-5Tx
ABSOLUTE RATINGS (limiting values)

| Symbol | Parameter |  |  | Value | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {DRM }} / \mathrm{V}_{\text {RRM }}$ | Repetitive peak off-state voltage |  | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ | 500 | V |
| $\mathrm{I}_{\text {( } \mathrm{RMS} \text { ) }}$ | RMS on-state current full cycle sine wave 50 to 60 Hz | TO92 | Tamb $=75^{\circ} \mathrm{C}$ | 0.2 | A |
|  |  | SO-8 | Tamb $=75^{\circ} \mathrm{C}$ | 0.2 | A |
| $I_{\text {TSM }}$ | Non repetitive surge peak on-state current Tj initial $=25^{\circ} \mathrm{C}$, full cycle sine wave |  | $\mathrm{F}=50 \mathrm{~Hz}$ | 7.3 | A |
|  |  |  | $\mathrm{F}=60 \mathrm{~Hz}$ | 8 | A |
| dl/dt | Critical rate of rise of on-state current $\mathrm{I}_{\mathrm{G}}=10 \mathrm{~mA}, \mathrm{tr}=100 \mathrm{~ns}$ |  | $\mathrm{F}=120 \mathrm{~Hz}$ | 20 | A/ $\mu \mathrm{s}$ |
| VPP | Non repetitive line peak pulse voltage |  | note 1 | 2 | kV |
| Tstg | Storage temperature range |  |  | -40 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Tj | Operating junction temperature range |  |  | 0 to +110 | ${ }^{\circ} \mathrm{C}$ |
| TI | Maximum lead temperature for soldering during 10s |  |  | 260 | ${ }^{\circ} \mathrm{C}$ |

note 1 : according to test described by IEC 1000-4-5 standard \& Figure 4.
SWITCH GATE CHARACTERISTICS (maximum values)

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{P}_{\mathrm{G}(\mathrm{AV})}$ | Average gate power dissipation | 0.1 | W |
| $\mathrm{I}_{\mathrm{GM}}$ | Peak gate current $\left(\mathrm{tp}=20_{\mu} \mathrm{s}\right)$ | 1 | A |
| $\mathrm{~V}_{\mathrm{GM}}$ | Peak positive gate voltage (respect to the pin COM) | 5 | V |

## THERMAL RESISTANCES

| Symbol | Parameter |  | Value | Unit |
| :---: | :--- | :---: | :---: | :---: |
| Rth (j-a) | Junction to ambient | TO92 | 150 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  |  | SO-8 | 150 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Rth (j-1) | Junction to leads for full AC line cycle conduction | TO92 | 60 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## ELECTRICAL CHARACTERISTICS

For either positive or negative polarity of pin OUT voltage respect to pin COM voltage

| Symbol | Test Conditions |  |  | Values | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| IGT | Vout $=12 \mathrm{~V}$ (DC) $\mathrm{R}_{\mathrm{L}}=140 \Omega$ | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ | MAX | 5 | mA |
| $V_{G T}$ | Vout $=12 \mathrm{~V}$ (DC) $\mathrm{R}_{\mathrm{L}}=140 \Omega$ | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ | MAX | 0.9 | V |
| $V_{G D}$ | $\mathrm{V}_{\text {OUT }}=\mathrm{V}_{\text {DRM }} \mathrm{R}_{\text {L }}=3.3 \mathrm{k} \Omega$ | $\mathrm{Tj}=110^{\circ} \mathrm{C}$ | MIN | 0.2 | V |
| $\mathrm{IH}^{\text {}}$ | lout $=100 \mathrm{~mA}$ gate open | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ | TYP | 20 | mA |
|  |  |  | MAX | tbd |  |
| I L | $\mathrm{I}_{\mathrm{G}}=20 \mathrm{~mA}$ | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ | TYP | 25 | mA |
|  |  |  | MAX | tbd |  |
| $\mathrm{V}_{\text {TM }}$ | lout $=0.3 \mathrm{~A} \quad \mathrm{tp}=380 \mu \mathrm{~s}$ | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ | MAX | 1.2 | V |
| IDRM IRRM | $\begin{aligned} & V_{\text {OUT }}=V_{\text {DRM }} \\ & V_{\text {OUT }}=V_{\text {RRM }} \end{aligned}$ | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ | MAX | 2 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{Tj}=110^{\circ} \mathrm{C}$ | MAX | 50 |  |
| dV/dt | Vout $=400 \mathrm{~V}$ gate open | $\mathrm{Tj}=110^{\circ} \mathrm{C}$ | MIN | 300 | V/us |
| (dl/dt)c | Turn off $=10 \mathrm{~ms}$, (dV/dt) $\mathrm{c}=5 \mathrm{~V} / \mu \mathrm{s}$ | $\mathrm{Tj}=110^{\circ} \mathrm{C}$ | MIN | 0.1 | A/ms |
|  | Turn off $=20 \mathrm{~ms},(\mathrm{dV} / \mathrm{dt}) \mathrm{c}=10 \mathrm{~V} / \mu \mathrm{s}$ |  |  | 0.15 |  |
| $\mathrm{V}_{\mathrm{CL}}$ | $\mathrm{ICL}=1 \mathrm{~mA} \quad \mathrm{tp}=1 \mathrm{~ms}$ | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ | TYP | 600 | V |

tbd = to be defined

PARAMETER DESCRIPTION

| Parameter Symbol | Parameter Description |
| :--- | :--- |
| $\mathrm{I}_{\mathrm{GT}}$ | Gate triggering current |
| $\mathrm{V}_{\mathrm{GT}}$ | Gate triggering voltage |
| $\mathrm{V}_{\mathrm{GD}}$ | Non triggering voltage |
| $\mathrm{I}_{\mathrm{H}}$ | Holding current |
| $\mathrm{I}_{\mathrm{L}}$ | Latching current |
| $\mathrm{V}_{\text {TM }}$ | On state voltage |
| $\mathrm{I}_{\mathrm{DRM}} / \mathrm{I}_{\mathrm{RRM}}$ | Forward or reverse leakage current |
| $\mathrm{dV} / \mathrm{dt}$ | Static pin OUT voltage rise |
| (dI/dt)c | Turn off current rate of decay |
| $\mathrm{V}_{\mathrm{CL}}$ | Clamping voltage |

## AC LINE SWITCH BASIC APPLICATION

The ACS102 device is well adapted to washing machine, dish washer, tumble drier, refrigerator, water heaters, and cookware. It has been designed especially to switch on \& off low power loads such as solenoid, valve, relay, dispenser, micro-motor, pump, fan, door lock, and low wattage lamps bulbs.

Pin COM : Common drive reference to connect to the power line neutral
Pin G : Switch Gate input to connect to the digital controller through a resistor
Pin OUT : Switch Output to connect to the load

This ACS switch is triggered with a negative gate current flowing out of the gate pin G . It can be driven directly by the digital controller through a resistor as shown on the typical application diagram. No protection device (zener or capacitor) are required between gate and COM terminals.
The SO-8 version allows to connect several ACS102 devices on the same cooling PCB pad which is the COM pin.
In appliances systems, the ACS102 switch intends to drive low power load in full cycle ON / OFF mode. The turn off commutation characteristics of these loads are described in table 1.
Thanks to its thermal and turn off commutation performances, the ACS102 switch is able to drive with no turn off aid snubber a load up to 0.2 A (door lock, lamp, relay, valve \& micro motor) when this load has to switch off within one half AC line cycle, and up to 0.3 A (pump, fan) when this load can switch off within one full AC line cycle.

Table 1: Low power load turn off commutation requirement (230V AC applications).

| LOAD | IRMS | POWER <br> FACTOR | (dI/dt)c | (dV/dt)c | TURN-OFF <br> DELAY |
| :--- | :---: | :---: | :---: | :---: | :---: |
| $(\mathrm{A} / \mathrm{ms})$ | $(\mathrm{V} / \mu \mathrm{s})$ | $(\mathrm{ms})$ |  |  |  |
| Door lock, lamp | $<0.2$ | 1 | $<0.1$ | $<0.15$ | $<10$ |
| Relay Valve <br> Dispenser <br> Micro-motor | $<0.2$ | $>0.7$ | $<0.1$ | $<5$ | $<10$ |
| Pump Fan | $<0.3$ | $>0.2$ | $<0.15$ | $<10$ | $<20$ |

TYPICAL APPLICATION DIAGRAM


## HIGH INDUCTIVE SWITCH-OFF OPERATION

At the end of the last conduction half-cycle, the load current reaches the holding current level $\mathrm{I}_{\mathrm{H}}$, and the ACS ${ }^{T M}$ switch turns off. Because of the inductance L of the load, the current flows through the avalanche diode D and decreases linearly to zero. During this time, the voltage across the switch is limited to the clamping voltage $\mathrm{V}_{\text {CL }}$.

The energy stored in the inductance of the load depends on the holding current $\mathrm{l}_{\mathrm{H}}$ and the inductance (up to 10 H ); it can reach about 20 mJ and is dissipated in the clamping diode section. The ACS switch sustains the turn off energy, because its clamping section is designed for that purpose.

Fig 1: Turn-off operation of the ACS102 switch with an electro valve: waveform of the gate current $\mathrm{I}_{\mathrm{G}}$, pin OUT current lout \& voltage $\mathrm{V}_{\text {OUT }}$.


Fig 2: ACS102 switch static characteristic.


## AC LINE TRANSIENT VOLTAGE RUGGEDNESS

The ACS102 switch is able to sustain safely the AC line transient voltages either by clamping the low energy spikes or by breaking over under high energy shocks, even with high turn-on current rates of increase.
The test circuit of the figure 3 is representative of the final ACS application and is also used to stress the ACS switch according to the IEC1000-4-5 standard conditions. Thanks to the load, the ACS switch sustains the voltage spikes up to 2 kV above the peak line voltage. It will breaks over safely even on resistive load where the turn on current rate of increase is high as shown on figure 4 . Such non repetitive test can be done 10 times on each AC line voltage polarity.

Fig. 3: Overvoltage ruggedness test circuit for resistive and inductive loads according to IEC 1000-4-5 standard.
$R=150 \Omega, L=5 \mu H, V P P=2 k V$.


Fig 5: Relative variation of gate trigger current versus junction temperature


Fig. 4: Current and Voltage of the ACS during IEC 1000-4-5 standard test with $R=150 \Omega$, $L=$ $5 \mu \mathrm{H} \& \mathrm{VPP}=2 \mathrm{kV}$.


Fig 6: Relative variation of holding \& latching currents versus junction temperature


Fig 7: Typical on state characteristics @ Tj max
$\mathrm{V}_{\mathrm{TO}}=0.85 \mathrm{~V} \& \mathrm{R}_{\mathrm{T}}=0.40 \Omega$ (maximum values) Pon $=V_{T O} \cdot 2 \cdot \sqrt{2} \cdot I_{T(R M S)} / \Pi+R_{T} \times I_{T(R M S)}{ }^{2}$


Fig. 9-1: Relative variation of the junction to ambient thermal impedance versus conducting pulse duration for the SO8. Standard foot print with $35 \mu \mathrm{~m}$ copper layout thickness.

Fig 8: Maximum RMS switch current versus ambient temperature on inductive load (PF>0.1) and a low repetitive rate ( $\mathrm{F}<0.1 \mathrm{~Hz}$ ) for both TO92 and SO8.


Fig. 9-2: Relative variation of the junction to ambient thermal impedance versus conducting pulse duration for the TO92.


## ORDERING INFORMATION



PACKAGE OUTLINE MECHANICAL DATA
SO-8


PACKAGE FOOT PRINT
SO-8


ACS102-5Tx

## PACKAGE OUTLINE MECHANICAL DATA

TO92 Plastic


| Ordering type | Marking | Package | Weight | Base qty | Delivery mode |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ACS102-5TA | ACS102 | TO92 | 0.2 g | 2500 | Bulk |
| ACS102-5TA-TR | ACS102 | TO92 | 0.2 g | 2000 | Tape \& reel |
| ACS102-5T1-TR | ACS102 | SO-8 | 0.11 g | 2500 | Tape \& reel |

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